OPB420AZ, OPB420BZ



Features:

- Non-contact switching
- Right Angle Sensor: LED in tower, photosensor in base
- Choice of output configuration
- Optical line can be broken in three axis
- 24" minimum, 26 AWG UL approved wire leads



Description:

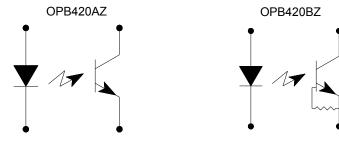
The OPB420 series optical switch consists of an infrared emitting diode (LED) and a phototransistor. The LED is mounted on the tower with the phototransistor mounted on the base of a right angle shape package. The L-Shape or right angle package configuration allows for an opaque object to block the light beam from a multitude of directions including the X-axis Y-axis and Z-axis. The optical center line between the emitter and photosensor is at 45° from the mounting base of the device. The OPB420AZ utilizes a phototransistor with a current output proportional to the input drive current of the LED. The OPB420BZ utilizes a phototransistor with a base-emitter resistance (RBE) which provides protection from low level light conditions. The OPB420BZ is ideal for applications that require an enhanced contrast ratio and immunity to background irradiance, such as detection of semi-transparent media.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact interruptive object sensing
- Tray-out sensor
- Low paper tray sensor
- Corner sensor
- Printers
- Copying machines
- Paper sorting equipment
- Amusement gaming equipment
- Door sensor
- Optical Switch

Part #	LED Wavelength	PhotoSensor		
OPB420AZ	000 nm	Phototransistor		
OPB420BZ	880 nm	R _{BE} Phototransistor		





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Electrical Specifications

Phototransistor Version

Power Dissipation (2)

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Absolute maximum natings (1,4 25 of amess other wise noted)			
Storage & Operating Temperature Range	-40° C to +85° C		
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] (1)	260° C		
Input Diode			
Continuous Forward Current	50 mA		
Peak Forward Current (1 μs pulse width, 300 pps)	1 A		
Reverse Voltage	2 V		
Power Dissipation ⁽²⁾	100 mW		
Output Phototransistor			
Collector-Emitter Breakdown Voltage			
OPB420AZ	30 V		
OPB420BZ	24 V		

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
Input Diode (See OP240 or OP265 for additional information)							
V _F	Forward Voltage	1.2	-	1.7	V	I _F = 20 mA	
I _R	Reverse Current	-	-	100	μΑ	V _R = 2 V	

Output Phototransistor (See OP505 or OP705 for additional information)

V _{(BR)CEO}	Collector-Emitter Breakdown Voltage OPB420AZ OPB420BZ	30 24	-	-	V	I _C = 1 mA I _C = 100 μA
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage OPB420AZ OPB420BZ	5.0 0.4	-	-	٧	Ι _Ε = 100 μΑ
I _{CEO}	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$

Combined

V _{CE(SAT)}	Collector-Emitter Saturation Voltage	-	-	0.4	٧	I _C = 250 μA, I _F = 20 mA
I _{C(ON)}	On-State Collector Current	1.0	ı	10.0	mA	V _{CE} = 5.0 V, I _F = 20 mA
I _{C(Off)}	Off-State Collector Current—OPB420BZ	-	1	450	μΑ	$V_{CE} = 5 \text{ V, } I_F = 1 \text{ mA}^{(5)}$

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly 1.67 mW/°C above 25 ° C..
- (3) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.
- (4) All parameters were tested using pulse technique.
- (5) Simulated optical path blocked with infrared semi-transparent object

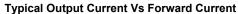
General Note

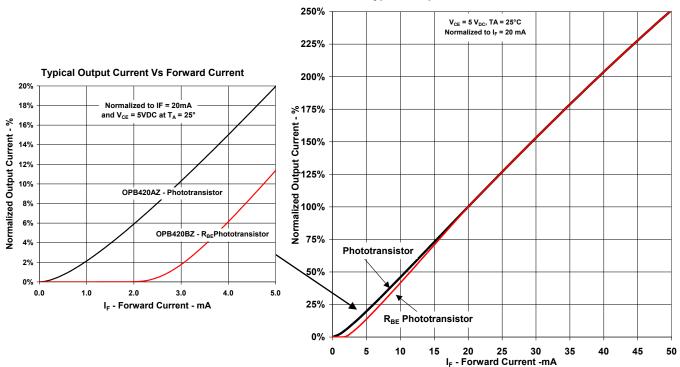
100 mW

OPB420AZ, OPB420BZ

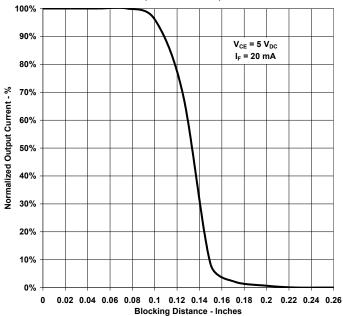


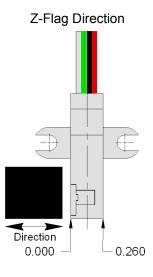
Performance





Typical Output Current Vs Distance (Z Axis Blocked)





General Note

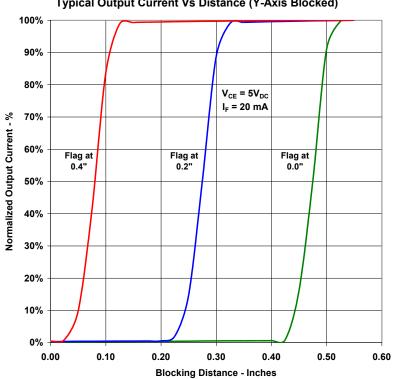
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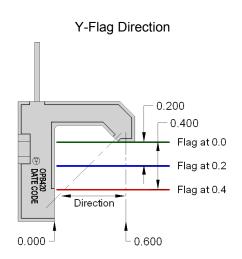
OPB420AZ, OPB420BZ



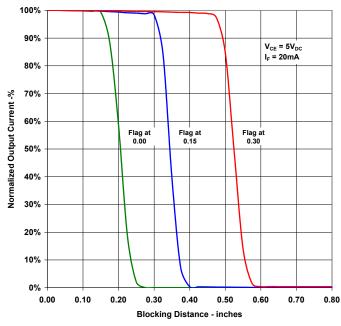
Performance

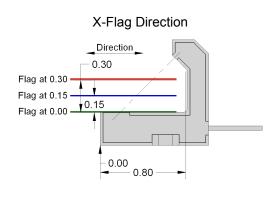






Typical Output Current Vs Distance X-Axis Blocked



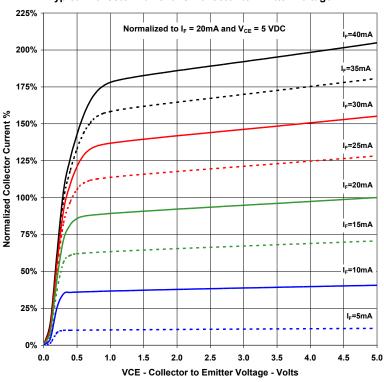


OPB420AZ, OPB420BZ

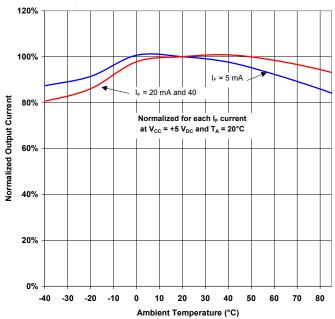


Performance

Typical Collector Current vs Collector to Emitter Voltage

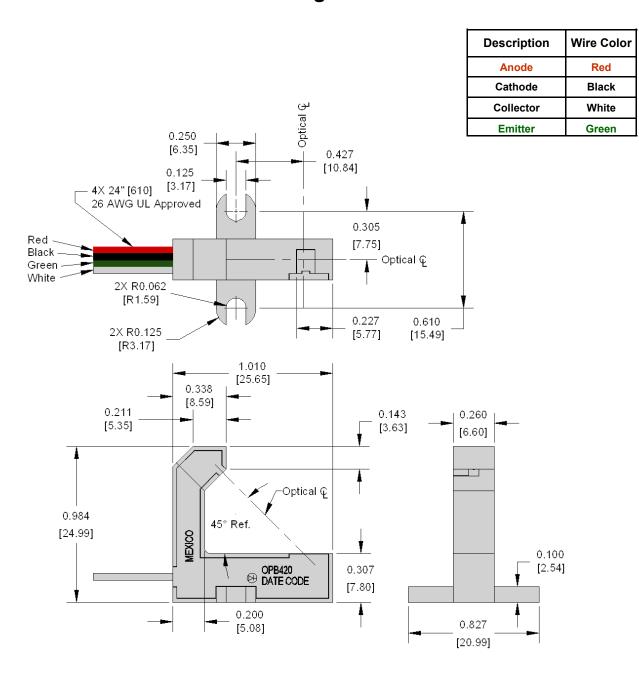


Typical Output Current vs Ambient Temperature





Packaging Mechanical Package Information



Dimensions are in Inches [Millimeters]

Tolerances ±0.010" [0.25mm]

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